

1 S 2662		Si-Di	=1S2660: 1000V	73b	=DO-9	-	-	-	-
1 S 2663		Si-Di	=1S2660: 1200V	73b	=DO-9	-	-	-	-
1 S 2664		Si-Di	=1S2660: 1400V	73b	=DO-9	-	-	-	-
1 S 2665		Si-Di	=1S2660: 1600V	73b	=DO-9	-	-	-	-
1 S 2666	Sak	Si-Di	P FRr, 100V, 80A, Uf<1,7V(300A), <300ns	73b	DO-30	-	-	-	-
1 S 2667		Si-Di	=1S2666: 200V	73b	DO-30	-	-	-	-
1 S 2668		Si-Di	=1S2666: 250V	73b	DO-30	-	-	-	-
1 S 2669	Sak	Si-Di	P FRr, 100V, 8A(Tc=100°), Uf<1,8V(30A), <300ns	-	-	-	-	-	-
1 S 2670		Si-Di	=1S2669: 250V	-	-	-	-	-	-
1 S 2671		Si-Di	=1S2669: 400V	-	-	-	-	-	-
1 S 2672		Si-Di	FRr, 200V, 0,8A, Uf<1,1V(0,8A), <200ns	31a	SOD-57	-	-	-	BY 201/2, BYT 52D, BYX 92/200, RGP 10D
1 S 2673		Si-Di	=1S2672: 300V	31a	SOD-57	-	-	-	BY 201/3, BYT 52G, BYX 92/300, RGP 10G
1 S 2674		Si-Di	=1S2672: 400V	31a	SOD-57	-	-	-	BY 201/4, BYT 52G, BYX 92/400, RGP 10G
1 S 2675		Si-Di	=1S2672: 500V	31a	SOD-57	-	-	-	BY 201/5, BYT 52J, RGP 10J
1 S 2676		Si-Di	=1S2672: 600V	31a	SOD-57	-	-	-	BY 201/6, BYT 52J, RGP 10J
1 S 2677		Si-Di	=1S2672: 700V	31a	SOD-57	-	-	-	BYT 52K, RGP 10K
1 S 2678		Si-Di	=1S2672: 800V	31a	SOD-57	-	-	-	BYT 52K, RGP 10K
1 S 2679		Si-Di	=1S2672: 1000V	31a	SOD-57	-	-	-	BYT 52M, RGP 10M
1 S 2685	Hit	Si-Di	VHF Tuning	71a(4mm)	SOD-23	-	-	-	BB 105, BB 205, BB 305, BB 405, BB 505++
1 S 2686	Njr	Si-Di	AFC	31a	DO-41	-	-	-	-
1 S 2687	Njr	Si-Di	AFC	31a	DO-41	-	-	-	-
1 S 2688	Njr	C-Di	AFC	31a	DO-41	-	-	-	-
1 S 2689	Njr	Si-Di	AFC	31a	DO-41	-	-	-	-
1 S 2692	Hit	Si-Di	VHF Band-S	71a(4mm)	SOD-23	-	-	-	BA 182, BA 243, BA 283, BA 483...484, ++
1 S 2701(R)	Nec	Si-Di	P Rr, 100V, 100A(Tc=96°), Uf<1,1V(300A)	-	-	-	-	-	-
1 S 2702(R)		Si-Di	=1S2701: 200V	-	-	-	-	-	-
1 S 2703(R)		Si-Di	=1S2701: 300V	-	-	-	-	-	-
1 S 2711	Tos	Si-Di	Rr, 1500V, 1,5A, Uf<1,2V(2A)	34a	DO-1	-	-	-	BY 228, BY 255, BY 400, BY 448
1 S 2712	Tos	Si-Di	Rr, S, 1800V, 1,4A, Uf<1,2V(2A), <2,2µs	34b	DO-1	-	-	-	-
1 S 2713	Tos	Si-Di	KV-Rr, 45kV, 2A, Uf<80V(10mA), <250µs	-	-	-	-	-	-
1 S 2714	Tos	Si-Di	P FRr, 100V, 6A(Tc=100°), Uf<1,4V(6A), <200ns	32	DO-4	-	-	-	1N3880...3883
1 S 2715		Si-Di	=1S2714: 200V	32	DO-4	-	-	-	1N3881...3883
1 S 2716		Si-Di	=1S2714: 300V	32	DO-4	-	-	-	1N3882...3883
1 S 2717		Si-Di	=1S2714: 400V	32	DO-4	-	-	-	1N3883
1 S 2718		Si-Di	=1S2714: 600V	32	DO-4	-	-	-	-
1 S 2719	Tos	Si-Di	P FRr, 100V, 30A(Tc=100°), Uf<1,4V(30A), <200ns	32	DO-5	-	-	-	1N3910...3913
1 S 2720		Si-Di	=1S2719: 200V	32	DO-5	-	-	-	1N3911...3913
1 S 2721		Si-Di	=1S2719: 300V	32	DO-5	-	-	-	1N3912...3913
1 S 2722		Si-Di	=1S2719: 400V	32	DO-5	-	-	-	1N3913
1 S 2723		Si-Di	=1S2719: 600V	32	DO-5	-	-	-	-
1 S 2724	Sak	Si-Di	Dual, 200V, 5A, Uf<0,95V(1,5A)	22f	SOT-9	-	-	-	-
1 S 2725		Si-Di	=1S2724: 400V	22f	SOT-9	-	-	-	-
1 S 2726		Si-Di	=1S2724: 600V	22f	SOT-9	-	-	-	-
1 S 2724R...2726R		Si-Di	=1S2724:	22n	SOT-9	-	-	-	-
1 S 2745	Tos	Si-Di	Rr, S, 750V, 2,5A, Uf<1,3V(4A), <1,3µs	34b	DO-1	RGP 30 M	31a	-	BY 228, BY 438, RGP 30K
1 S 2746		Si-Di	=1S2745: 800V	34b	DO-1	RGP 30 M	31a	-	BY 228, BY 438, RGP 30K
1 S 2747		Si-Di	=1S2745: 1000V	34b	DO-1	RGP 30 M	31a	-	BY 228, BY 438, RGP 30M
1 S 2756	Tos	Si-Di	Rr, 400V, 1A, Uf<1,2V(1,5A), <2,5µs	31a	DO-15	-	-	-	BY 201/4, BYX 55/600, RGP 10G
1 S 2757		Si-Di	=1S2756: 600V	31a	DO-15	-	-	-	BY 201/6, BYX 55/600, RGP 10J
1 S 2758	Nec	Si-Di	Rr, 1000V, 3A, Uf<1V(3A)	31a	SOD-64	-	-	-	BY 255, BYW 17/1000, G3M, 1N5408, ++
1 S 2759		Si-Di	=1S2758: 1200V	31a	SOD-64	-	-	-	BY 255, BYW 17/1200
1 S 2760		Si-Di	=1S2758: 50V	31a	SOD-64	-	-	-	BY 251...255, BYW 17/100, 1N5402...08, ++
1 S 2761		Si-Di	=1S2758: 100V	31a	SOD-64	-	-	-	BY 251...255, BYW 17/100, 1N5402...08, ++
1 S 2762		Si-Di	=1S2758: 200V	31a	SOD-64	-	-	-	BY 251...255, BYW 17/200, 1N5402...08, ++
1 S 2763		Si-Di	=1S2758: 300V	31a	SOD-64	-	-	-	BY 252...255, BYW 17/400, 1N5403...08, ++
1 S 2764		Si-Di	=1S2758: 400V	31a	SOD-64	-	-	-	BY 252...255, BYW 17/400, 1N5404...08, ++
1 S 2765		Si-Di	=1S2758: 500V	31a	SOD-64	-	-	-	BY 253...255, BYW 17/600, 1N5406...08, ++
1 S 2766		Si-Di	=1S2758: 600V	31a	SOD-64	-	-	-	BY 253...255, BYW 17/600, 1N5406...08, ++
1 S 2766 A		Si-Di	=1S2766: contr.av.	31a	SOD-64	-	-	-	BYM 56C, BYW 18/600, BYW 84...86
1 S 2767		Si-Di	=1S2758: 700V	31a	SOD-64	-	-	-	BY 254...255, BYW 17/800, 1N5407...08, ++
1 S 2767 A		Si-Di	=1S2767: contr.av.	31a	SOD-64	-	-	-	BYM 56D, BYW 18/800, BYW 85...86
1 S 2768		Si-Di	=1S2758: 800V	31a	SOD-64	-	-	-	BY 254...255, BYW 17/800, 1N5407...08, ++
1 S 2768 A		Si-Di	=1S2768: contr.av.	31a	SOD-64	-	-	-	BYM 56D, BYW 18/800, BYW 85...86
1 S 2769	Nec	Ref-Di	6...7V(7,5mA), ±0,02%/°C, <20Ω, 0,25W	2a	TO-18	-	-	-	BZV 10, BZV 27, 1N4580
1 S 2770		Ref-Di	=1S2769: ±0,01%/°C	2a	TO-18	-	-	-	BZV 10, BZV 27, 1N4580
1 S 2771		Ref-Di	=1S2769: ±0,005%/°C	2a	TO-18	-	-	-	BZV 11, BZV 28, 1N4581
1 S 2772		Ref-Di	=1S2769: ±0,002%/°C	2a	TO-18	-	-	-	BZV 12, BZV 29, 1N4582
1 S 2773		Ref-Di	=1S2769: ±0,001%/°C	2a	TO-18	-	-	-	BZV 13, BZV 30, 1N4583
1 S 2774		Ref-Di	=1S2769: ±0,0005%/°C	2a	TO-18	-	-	-	BZV 14, BZV 31, 1N4584
1 S 2775	Tos	Si-Di	Rr, 200V, 0,5A, Uf<1,4V(1A), <2µs	31a	DO-15	-	-	-	BY 295/200, BY 406...407, BYX 55/600,++
1 S 2776		Si-Di	=1S2775: 400V	31a	DO-15	-	-	-	BY 295/400, BY 407, BYX 55/600, ++
1 S 2777		Si-Di	=1S2775: 600V	31a	DO-15	-	-	-	BY 295/600, BY 407, BYX 55/600, ++
1 S 2778	Sak	Si-Di	Rr, 200V, 2,7A, Uf<1,2V(3A)	31a	SOD-64	-	-	-	BY 251...255, GP 30D, MR 502...510, ++
1 S 2779		Si-Di	=1S2778: 400V	31a	SOD-64	-	-	-	BY 252...255, GP 30G, MR 504...510, ++
1 S 2780		Si-Di	=1S2778: 600V	31a	SOD-64	-	-	-	BY 253...255, GP 30J, MR 506...510, ++
1 S 2781		Si-Di	=1S2778: 800V	31a	SOD-64	-	-	-	BY 254...255, GP 30K, MR 508...510, ++
1 S 2782		Si-Di	=1S2778: 1000V	31a	SOD-64	-	-	-	BY 228, BY 255, GP 30M, MR 510, ++
1 S 2783	Njr	C-Di	Tuning	31a	DO-41	-	-	-	-
1 S 2784	Stl	Si-Br	Br Rr, 100V, 0,5A	42	(8x8x5mm)	-	-	-	B100C500, etc.
1 S 2785		Si-Br	=1S2784: 200V	42	(8x8x5mm)	-	-	-	B200C500, etc.
1 S 2786		Si-Br	=1S2784: 400V	42	(8x8x5mm)	-	-	-	B400C500, etc.
1 S 2787	Rhm	Si-Di	SS, 40V, 0,05A, <3ns	31a	DO-35	1N4148	31a	-	BA 318, BAY 38, 1N4148...49, 1N4446...49++
1 S 2788	Rhm	Si-Di	SS, 25V, 0,05A, <3ns	31a	DO-35	1N4148	31a	-	BA 318, BAY 38, 1N4148...49, 1N4446...49++
1 S 2789	Tos	C-Di	UHF Tuning	71a(4mm)	SOD-23	-	-	-	BB 105, BB 205, BB 305, BB 405, BB 505++
1 S 2790	Hit	C-Di	VHF AFC	31a	DO-35	-	-	-	BA 125, BB 119, 1SV114, 1SV125
1 S 2791	Hit	Si-Di	Schottky, UHF Mx, 5V, 30mA, F=7dB(887MHz)	31a	DO-7	-	-	-	BA 480...481, BAR 19, BAT 29
1 S 2792	Sak	Si-Di	P FRr, 100V, 20A(Tc=90°), Uf<2V(60A), <300ns	32b	=DO-5	-	-	-	1N3900R...3903R
1 S 2793		Si-Di	=1S2792: 250V	32b	=DO-5	-	-	-	1N3902R...3903R
1 S 2794		Si-Di	=1S2792: 400V	32b	=DO-5	-	-	-	1N3903R
1 S 2795	Tos	Si-Di	P Rr, 400V, 12A(Tc=40°), Uf<1,2V(12A)	32	DO-5	-	-	-	-
1 S 2796		Si-Di	=1S2795: 600V	32	DO-5	-	-	-	-
1 S 2797		Si-Di	=1S2795: 800V	32	DO-5	-	-	-	-
1 S 2798		Si-Di	=1S2795: 1000V	32	DO-5	-	-	-	-